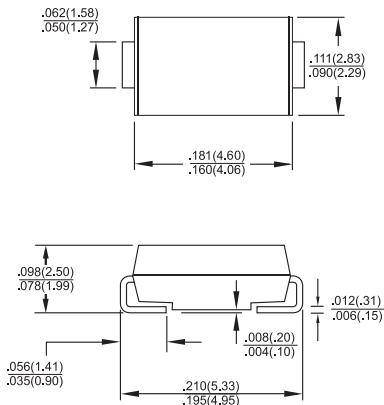




Features

- ✦ Glass passivated junction chip
- ✦ For surface mounted application
- ✦ Low profile package
- ✦ Built-in strain relief
- ✦ Ideal for automated placement
- ✦ Easy pick and place
- ✦ Superfast recovery time for high efficiency
- ✦ Glass passivated chip junction
- ✦ High temperature soldering:
260°C/10 seconds at terminals
- ✦ Plastic material used carries Underwriters
Laboratory Classification 94V-0



Mechanical Data

- ✦ Cases: Molded plastic
- ✦ Terminals: Pure tin plated, lead free.
- ✦ Polarity: Indicated by cathode band
- ✦ Packing: 12mm tape per EIA STD RS-481
- ✦ Weight: 0.093 gram

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	ES 2AA	ES 2BA	ES 2CA	ES 2DA	ES 2FA	ES 2GA	ES 2HA	ES 2JA	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	2.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50								A
Maximum Instantaneous Forward Voltage @ 2.0A	V_F	0.95			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ Cat Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$	I_R	10 350								μA μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	35								nS
Typical Junction Capacitance (Note 2)	C_j	25			20					pF
Maximum Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$	75 20								$^\circ\text{C} / \text{W}$
Operating Temperature Range	T_J	-55 to +150								$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150								$^\circ\text{C}$

- Notes:
1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 2. Measured at 1 MHz and Applied $V_R=4.0$ Volts
 3. Units Mounted on P.C.B. 0.2" x 0.2" (5mm x 5mm) Pad Areas

RATINGS AND CHARACTERISTIC CURVES (ES2AA THRU ES2JA)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

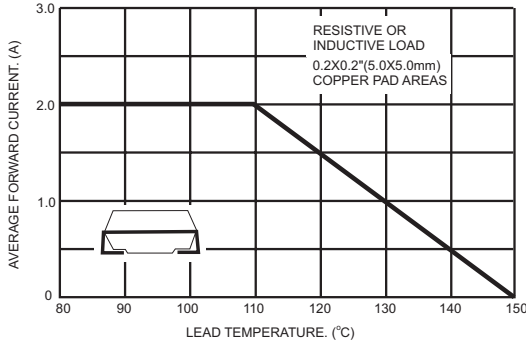


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

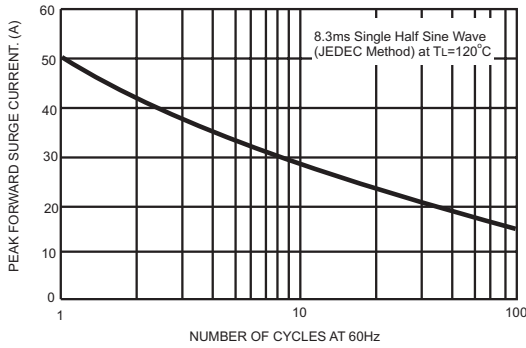


FIG.4- TYPICAL JUNCTION CAPACITANCE

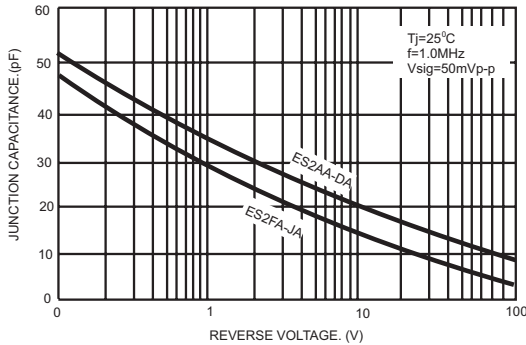


FIG.2- TYPICAL REVERSE CHARACTERISTICS

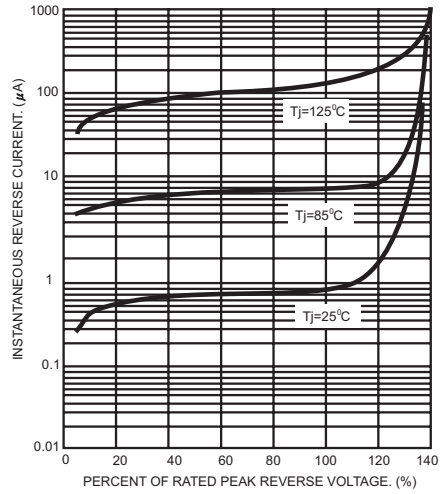


FIG.5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

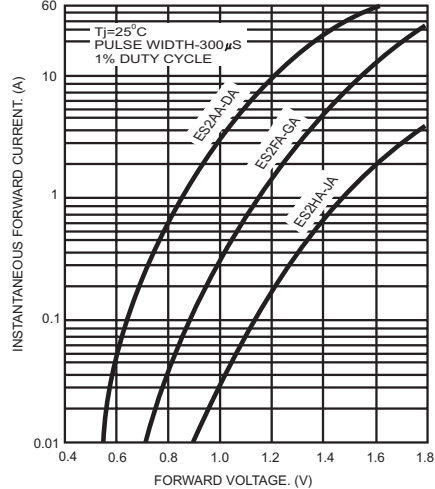
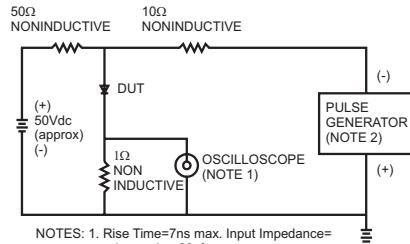


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



- NOTES: 1. Rise Time=7ns max. Input Impedance=1 megohm 22pf
2. Rise Time=10ns max. Source Impedance=50 ohms

